

温补振荡器 Temperature Compensated Crystal Oscillator: K(V)T16CS

Feature 特征

- Ultra-miniature 1.6x1.2mm package; Clipped Sine wave output for low EMI 超小型 1610 封装削峰正弦波输出
- Wide frequency range and tight frequency stability $\pm 1\text{ppm}$ over -40°C to $+85^\circ\text{C}$ 频率范围宽, 频率稳定性高
- VCTCXO option allows frequency tuning via control voltage 支持通过控制电压进行频率微调
- Ideal for GPS, communication, industrial, and measurement systems 适用于 GPS, 通信设备, 工业控制和测量系统等



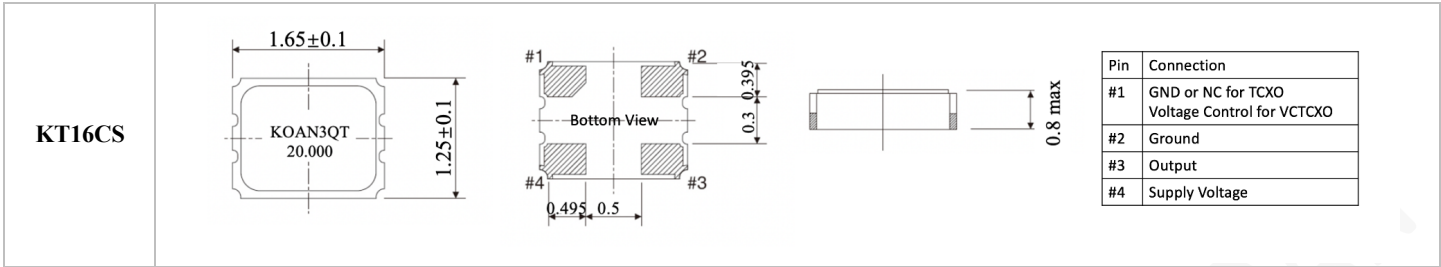
General Specifications 规格参考

PARAMETER	性能参数	K(V)T16CS				
Supply Voltage	工作电压	+1.8V; +2.5V				
Frequency Range	频率范围	13.0~52.0MHz				
Standard Frequency	通用频率	16.368, 16.369, 19.2, 26, 33.6, 38.4, 52MHz				
Output Waveform	输出波形	Clipped Sine Wave				
Output Load	输出负载	10KΩ/10pF				
Output Logic	输出电平	0.8Vp-p min				
Initial Calibration Tolerance	调整频差	±2.0ppm max (After 2 times reflows)				
Current Consumption	工作电流	2.5mA max				
Frequency Stability 频率稳定性 VS						
Operating Temperature Range	温度范围	见下表				
Frequency Stability	温度频差					
Load Change	负载变化	±0.2ppm (Load±5%)				
Voltage Change	电压变化	±0.2ppm (Vcc±5%)				
Aging	老化率	±1.0ppm/year max				
Reflow	回流焊	±1.0ppm max				
Control Voltage Range	控制电压范围	0.9±0.6V@1.8Vdd; 1.4±1.0V @2.5Vdd				
Frequency Tuning Range	频率调节范围	±8ppm min.				
Phase Noise @10MHz	相位噪声 Max (dBc/Hz)	-75	-110	-125	-145	-150
		10Hz	100Hz	1kHz	10kHz	100kHz
Input Impedance	输入电阻	100KΩ min.				
Start-up Time	起振时间	2.0ms max.				
Storage Temperature Range	储存温度范围	-55°C~+125°C				

Frequency Stability 温度频差 VS Operating Temperature Range 温度范围							
Temp. Code	Temp.\ppm	± 0.5	± 1.0	± 2.0	± 2.5	± 3.0	± 5.0
A	$-10\sim 60^\circ\text{C}$	o	o	o	o	o	o
B	$-20\sim 70^\circ\text{C}$	o	o	o	o	o	o
C	$-40\sim 85^\circ\text{C}$		o	o	o	o	o

NOTE: Please consult for other specifications 若有其它规格需求请告知

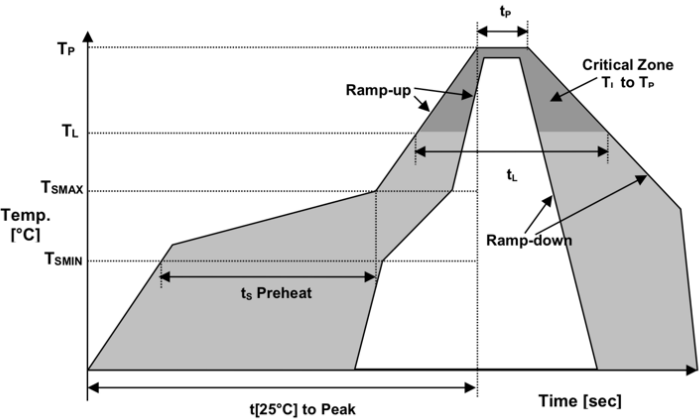
Outline Dimensions (Unit: mm) 外形尺寸



Part Number Guide 产品编号

<u>K(V)T16CS</u>	-	<u>20.000</u>	-	<u>33</u>	-	<u>C</u>	-	<u>01</u>	-	<u>NS</u>
↓		↓		↓		↓		↓		↓
型号	-	标称频率	-	工作电压	-	工作温度	-	温度频差	-	特殊要求
‘KT’:温补系列 KT: TCXO KVT: VCTCXO ‘16’: 封装尺寸 1.6x1.2mm ‘CS’: 输出波形 Clipped Sine								A5 = ±0.5ppm 01 = ±1.0ppm 02 = ±2.0ppm 025 = ±2.5ppm 03 = ±3.0ppm 05 = ±5.0ppm		
		(In MHz)	18=1.8V 25=2.5V		A: -10~+60°C B: -20~+70°C C: -40~+85°C		‘NS’:特殊要求			

Reflow Profile 回流焊



Temperature Min Preheat	最低预热温度	T_{smin}	150°C
Temperature Max preheat	最高预热温度	T_{smax}	200°C
Time (T_{smin} to T_{smax})	时间差	T_s	60~120 sec
Temperature	温度	T_L	217°C
Peak Temperature	最高温	T_p	260 °C
Ramp-up Rate	升温速度	R_{up}	3°C/sec max
Ramp-down Rate	降温速度	R_{down}	6°C/sec max
Time within 5°C of Peak Temperature	最高温度停留时间	t_p	30 sec
Time $t[25^\circ\text{C}]$ to peak temperature	25度到最高温度时间	$t[25^\circ\text{C}]$ to peak	480 sec
Time	时间	t_L	60~150 sec